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## Brief on PCB Modeling for Sub-THz Transceiver Module Design

Mohamed Habashy Mubarak (National Institute of Information and Communications Technology, Japan), Shinsuke Hara (National Institute of Information and Communications Technology, Japan), Satoru Tanoi (National Institute of Information and Communications Technology, Japan), Tatsuo Hagino (National Institute of Information and Communications Technology, Japan), Issei Watanabe (National Institute of Infomation and Communications Technology, Japan), Akifumi Kasamatsu (National Institute of Information and Communications Technology, Japan) ..... 1

## A 60 GHz Up-Conversion Mixer in 22 nm FD-SOI CMOS With Back-Gate Mode Switching

Xin Xu (TU Dresden, Germany), Jens Wagner (Technische Universität Dresden & Chair for Circuit Design and Network Theory, Germany), Frank Ellinger (Technische Universität Dresden, Germany) ..... 5

## A Distributed Model With a High Scaling Accuracy for GaN HEMTs Up to 100 GHz

Yutaro Yamaguchi (Mitsubishi Electric Corporation, Japan), Ken Kudara (Mitsubishi Electric Corporation, Japan), Shintaro Shinjo (Mitsubishi Electric Corporation, Japan), Koji Yamanaka (Mitsubishi Electric Corporation, Japan), Yasuyuki Miyamoto (Tokyo Institute of Technology, Japan) ..... 8

## A Ka-Band Three-Stage GaN MMIC Doherty Power Amplifier With Wideband Tee-Line Doherty Network for 5G Applications

Keigo Nakatani (Mitsubishi Electric Corporation, Japan), Yutaro Yamaguchi (Mitsubishi Electric Corporation, Japan), Ko Kanaya (Mitsubishi Electric Corporation, Japan), Shintaro Shinjo (Mitsubishi Electric Corporation, Japan), Akihito Hirai (Mitsubishi Electric Corporation, Japan) ..... 11

## A 1.4-mW Ka-Band Low Noise Amplifier Using Self-Resonant Transformer Matching in 90-nm CMOS Process

Yu-Hua Cheng (National Taiwan University, Taiwan), Chau-Ching Chieng (Institute of Astronomy and Astrophysics, Academia Sinica, Taiwan), Yunshan Wang (National Taiwan University, Taiwan), Huei Wang (National Taiwan University, Taiwan) ..... 14

## A -193.1dBc/Hz FOM 1.08mW Low Power 10GHz VCO in 22nm CMOS Technology

Xiao Luo (Tsinghua University, China), Songping Mai (Tsinghua University, China), Xian Tang (Tsinghua University, China), Haigang Feng (Tsinghua University, China) ..... 17

## I-V Global Parameter Extraction for Industry Standard FinFET Compact Model Using Deep Learning

Fredo P Chavez (Macquarie University, Australia), Jen-Hao Chen (University of California at Berkeley, Australia), Chien-Ting Tung (University of California at Berkeley, Australia), Chenming Hu (University of California Berkeley USA, USA), Sourabh Khandelwal (Macquarie University, Australia) ..... 20

## An Ultra-Wide Tuning Range SiGe VCO With 192.5dBc/Hz FoMT Using 6-Bit Switched Capacitor Bank and Centrosymmetric Core Layout

Rui Zhang (Southeast University, China), Zhe Chen (Southeast University, China), Jixin Chen (Southeast University, China), Wei Hong (Southeast University, China) ..... 23

## A 3D Printed Beam-Shaping Transmissive Metasurface for Antenna-In-Package Applications

Zhiwei Yin (University of Technology Sydney, Australia), Jiaqi Cai (Beijing University of Posts and Telecommunications, China), Jianfeng Zhu (University of Technology, Sydney, Australia), Jiejin Lai (University of Technology Sydney, Australia), Yang Yang (University of Technology Sydney, Australia) ..... 26

## A 5 to 11.1 GHz Quad-Core Quad-Mode Octave Tuning-Range CMOS LC VCO

Dawei Wang (Tsinghua University, China), Jian Zhang (Tsinghua University, China), Ruitao Wang (Tsinghua University, China), Chenguang Li (Tsinghua University, China), Yan Wang (Tsinghua University, China) ..... 29

## High-Power and Small-Size CMOS T/R Switch Using Stacked Inductor

Chia-Chun Chen (National Taiwan University, Taiwan), Jia-Wei Yei (National Taiwan University, Taiwan), Zi-Hao Fu (National Taiwan University, Taiwan), Kun-You Lin (National Taiwan University, Taiwan) ..... 32

## Wideband 5-Bit Vector-Sum Phase Shifter for 5G Millimeter-Wave Applications

Wen-Chen Lee (National Taiwan University, Taiwan), Zi-Hao Fu (National Taiwan University, Taiwan), Jia-Wei Yei (National Taiwan University, Taiwan), Kun-You Lin (National Taiwan University, Taiwan) ..... 35

## Broadband CMOS Power Amplifier Using Novel Current Mode Combiner for Ka-Band Applications

Anik Batabyal (Indian Institute of Technology, Bombay, India), Santosh Kumar Khylia (IIT Bombay, India), Rajesh Zele (Indian Institute of Technology Bombay (IIT Bombay), India), Huei Wang (National Taiwan University, Taiwan) ..... 38

## 20GHz-Band Low Backlobe Vivaldi Endfire Antenna Array for Digital Beamforming Transmitter Antenna Module

Junhao Zhang (University of Tohoku, Japan), Koki Furuchi (Tohoku University, Japan), Noriharu Suematsu (Tohoku University, Japan) ..... 41

## Automatic Dual-Box Digital Predistortion Calibration With Residual Elimination for Quadrature Digital Transmitters

Luyi Guo (Fudan university, China, Hong Kong), Yun Yin (Fudan University, Hong Kong) ..... 44

## A Single-Ended 4-38 GHz SiGe Dual-Modulus Prescaler for Wide-Band Frequency Synthesizers

Zongxiang Wang (Southeast University, China), Jixin Chen (Southeast University, China), Debin Hou (MISIC Microelectronics, China), Zhe Chen (Southeast University, China), Peigen Zhou (Southeast University, China), Wei Hong (Southeast University, China) ..... 47

## Design of 100 GHz Heterogeneous IPD Integrated Antenna and Bandpass Filter

Ta-Yeh Lin (Taiwan Semiconductor Research Institute, National Applied Research Laboratories, Taiwan), Shuw-Guann Lin (Taiwan Semiconductor Research Institute, National Applied Research Laboratories, Taiwan), Yin-Cheng Chang (Taiwan Semiconductor Research Institute, National Applied Research Laboratories, Taiwan, Taiwan), Chaoping Hsieh (Taiwan Semiconductor Research Institute, National Applied Research Laboratories, Taiwan, Taiwan), Da-Chiang Chang (Taiwan Semiconductor Research Institute, National Applied Research Laboratories, Taiwan, Taiwan) ..... 50

## A Ka-Band Low-Noise High-Gain Frontend Receiver in Monolithic E-Mode PINHEMT Technology for Millimeter-Wave Radiometers

Wei-Cheng Chen (National Central University, Taiwan), Hong-Yeh Chang (National Central University, Taiwan) ..... 53

## A Novel and Simplified Topology for Vector-Sum Phase Shifters

Trong Khoa Ho (Monash University, Australia), Yang Yang (University of Technology Sydney, Australia), Xi Zhu (University of Technology Sydney, Australia), Nemai Karmakar (MONASH University, Australia) ..... 56

<i>Design of Low Power Ka-Band Frequency Doubler in 45-nm CMOS-SOI With 45dBc Fundamental Rejection at Center Frequency</i>	60
Robert Nericua (University of Technology Sydney, Australia), Jim Darrell Ang (University of Technology Sydney, Australia), Xi Zhu (University of Technology Sydney, Australia) .....	
<i>Sub-Terahertz-Band On-Chip 2×2 Beam-Forming Array Antenna Using a Compact 2-D BFN on 45nm SOI CMOS</i>	63
Jean Temga (Silicon Austria Labs & Research Institute of Electrical Communication, Tohoku University, Austria), Mizuki Motoyoshi (Shizuoka Institute of Science and Technology, Japan), Noriharu Suematsu (Tohoku University, Japan) .....	
<i>Additively Manufactured Wideband Millimeter-Wave Sidelobe Suppression of Metalens Antenna</i>	67
Jiaqi Cai (Beijing University of Posts and Telecommunications, China), Weiping Chen (Beijing University of Posts and Telecommunications, China), Xuehan Wang (Beijing University of Posts and Telecommunications, China), Shufang Li (Beijing University of Posts and Telecommunications, China), Li Deng (Beijing University of Posts and Telecommunications, China), Yang Yang (University of Technology Sydney, Australia) .....	
<i>Varactor Diode Tunability Enhancement by Means of a Non-Foster Negative Capacitor on Linvill's NIC</i>	70
Alexander Leontyev (Saint Petersburg Electrotechnical University LETI, Russia), Nikita Kalmykov (Saint Petersburg Electrotechnical University, Russia), Dmitry Kholodnyak (Saint Petersburg Electrotechnical University LETI, Russia) .....	
<i>A D-Band Wideband Double-Balanced Source-Driven Up-Conversion Mixer in 40-nm CMOS</i>	73
Toshiaki Abe (Tokyo University of Science, Japan), Shinsuke Hara (National Institute of Information and Communications Technology, Japan), Akifumi Kasamatsu (National Institute of Information and Communications Technology, Japan), Yohtaro Umeda (Tokyo University of Science, Japan), Kyoya Takano (Tokyo University of Science, Japan) .....	
<i>Design Method for Negative Refractive Index Metasurface Lenses by Using a One-Dimensional Distributed Transmission-Line Model</i>	76
Tsutomu Nagayama (Kagoshima University, Japan) .....	
<i>A Straightforward Equivalent Circuit Approach for Characteristic Evaluation of Capacitor-Based Loaded-Line Phase Shifter</i>	79
Zulfi Zulfi (Telkom University, Indonesia), Trasma Yunita (Telkom University, Indonesia), Achmad Munir (Institut Teknologi Bandung, Indonesia) .....	
<i>Development of Compact Unequal Power Divider Based on Wilkinson Topology for Wireless Navigation System</i>	82
Arinil Haq Salsabila (Institut Teknologi Bandung, Indonesia), Zulfi Zulfi (Telkom University, Indonesia), Effrina Hamid (Institut Teknologi Bandung, Indonesia), Achmad Munir (Institut Teknologi Bandung, Indonesia) .....	
<i>A 286-299GHz Dual-Core Push-Push VCO With Harmonic Enhancement in 130-nm SiGe BiCMOS Technology</i>	85
Zhu Wentao (Southeast University, China), Rui Zhang (Southeast University, China), Jixin Chen (Southeast University, China), Wei Hong (Southeast University, China) .....	